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100	protected element	312	operating region
101	substrate	313	source electrode
102	operating layer	315	drain electrode
103	source region	317	gate electrode
104	drain region	320	gate metal layer
105	gate electrode	330	pad metal layer
106	source electrode	350	peripheral n ⁺ - type region
107	drain electrode	S	source terminal
112	gate wiring	D	drain terminal
113	source wiring	G	gate terminal
114	drain wiring	SP	source pad
115	diode	DP	drain pad
120	wiring	GP	gate pad
125	insulated layer	IN	common input terminal
200	protecting element	Ctl-1	control terminal
201	first n ⁺ - type region	Ctl-2	control terminal
202	second n ⁺ - type region	OUT1	output terminal
203	insulating region	OUT2	output terminal
203a	semi-insulating region	INPad	common input terminal pad
203b	insulated region	Ctl-1Pad	control terminal pad
204	metal electrode	Ctl-2Pad	control terminal pad
205	insulating film	OUT1Pad	output terminal pad
206	metal layer	OUT2Pad	output terminal pad